

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





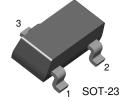




FJV4112R

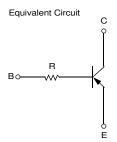
Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R=47K Ω)
- Complement to FJV3112R



1. Base 2. Emitter 3. Collector





PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	-40	V
V _{CEO}	Collector-Emitter Voltage	-40	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current	-100	mA
P _C	Collector Power Dissipation	200	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

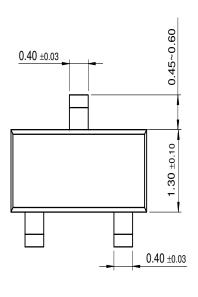
Electrical Characteristics $T_a=25^{\circ}C$ unless otherwise noted

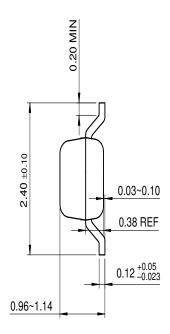
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I_{C} = -100 μ A, I_{E} =0	-40			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = -1 \text{ mA}, I_B = 0$	-40			V
I _{CBO}	Collector Cut-off Current	V _{CB} = -30V, I _E =0			-0.1	μΑ
h _{FE}	DC Current Gain	V_{CE} = -5V, I_{C} = -1mA	100		600	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = -10mA, I _B = -1mA			-0.3	V
C _{ob}	Output Capacitance	V_{CB} = -10V, I_{E} =0 f=1MHz		5.5		pF
f _T	Current Gain Bandwidth Product	V _{CE} = -10V, I _C = -5mA		200		MHz
R	Input Resistor		32	47	62	ΚΩ

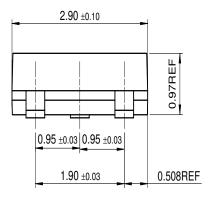
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Package Dimensions

SOT-23







Dimensions in Millimeters

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Rev. I1

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Definition of Terms

Datasheet Identification	Product Status	Definition
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